# PS30U45(F,B,H)CT thru PS30U120(F,B,H)CT

# 30A Schottky Barrier Rectifier

## **FEATURE**

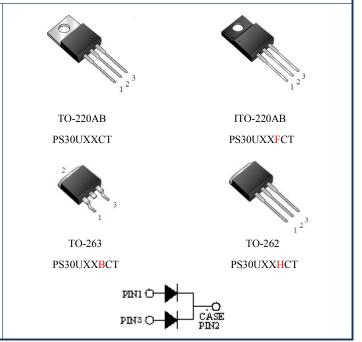
- High current capability
- Ultra low forward voltage drop
- Low power loss, high efficiency
- High surge capability
- High ESD capability
- High temperature soldering guaranteed: 260°C/10s/0.25"(6.35mm) from case

#### **MECHANICAL DATA**

- Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy
- Mounting position: any

#### TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters and polarity protection application.



Ratings at 25°C ambient temperature unless otherwise specified, Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

# **MAXIMUM RATINGS**

| Parameter   |              | Symbol             | PS30U45<br>CT | PS30U60<br>CT | PS30U100<br>CT | PS30U120<br>CT | units |
|---|--------------|--------------------|---------------|---------------|----------------|----------------|-------|
| Maximum Recurrent Peak Reverse Voltage  |              | $V_{ m RRM}$       | 45            | 60            | 100            | 120            | V     |
| Maximum RMS Voltage   |              | $V_{ m RMS}$       | 32            | 42            | 70             | 84             | V     |
| Maximum DC Blocking Voltage   |              | $V_{ m DC}$        | 45            | 60            | 100            | 120            | V     |
| Maximum Average Forward Rectified   | total device | 7                  | 30.0          |               |                |                | A     |
| Current at $T_{\rm C}$ =90°C  | per diode    | I <sub>F(AV)</sub> | 15.0          |               |                |                |       |
| Peak Forward Surge Current 8.3ms Single Half sine-wave superimposed on rate load per diode (JEDEC method) |              | $I_{ m FSM}$       | 175           |               |                |                |       |
| Junction Capacitance (Note1)  |              | CJ                 | 780 500       |               | 00             | pF             |       |
| Storage Temperature Range   |              | T <sub>STG</sub>   | -55 to +150   |               |                |                | °C    |
| Operation Temperature Range   |              | $T_{ m J}$         | -55 to +150   |               |                |                | °C    |

# **ELECTRONICAL CHARACTERISTICS**

| ELECTROPICAL CHARACTERISTICS                           |                        |                  |               |               |                |                |       |  |
|--|------------------------|------------------|---------------|---------------|----------------|----------------|-------|--|
| Parameter  |                        | Symbol           | PS30U45<br>CT | PS30U60<br>CT | PS30U100<br>CT | PS30U120<br>CT | units |  |
| Maximum Forward Voltage Drop per diode at 15A (Note 2) |                        | $V_{\mathrm{F}}$ | 0.55          | 0.60          | 0.78           | 0.85           | V     |  |
| Maximum DC Reverse Current at rated                    | @ T <sub>C</sub> =25°C | 7                | 0.            | 25            | 0.1            |                |       |  |
| DC blocking voltage (Note 2)                           | $@.T_{C}=100^{\circ}C$ |                  | 50.0          |               | 30.0           |                | mA    |  |

## THERMAL CHARACTERISTICS

| Parameter                           | Symbol               | ITO-220 | TO-220 | TO-262<br>TO-263 | units |
|-------------------------------------|----------------------|---------|--------|------------------|-------|
| Typical Thermal Resistance (Note 3) | R <sub>th (JC)</sub> | 3.0     | 2.0    | 2.0              | °C/W  |

# Note:

- 1. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc.
- 2. Pulse test: 300 µs pulse width, 1% duty cycle.
- 3. Thermal Resistance from Junction to Case Mounted on heatsink.